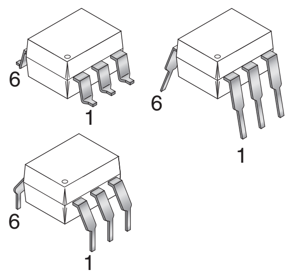
GENERAL PURPOSE 6-PIN PHOTOTRANSISTOR OPTOCOUPLERS

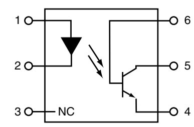
FAIRCHILD SEMICONDUCTOR®

4N25	**4N26**	**4N27**	**4N28**	**4N35**	**4N36**
4N37	**H11A1**	**H11A2**	**H11A3**	**H11A4**	**H11A5**

WHITE PACKAGE (-M SUFFIX)

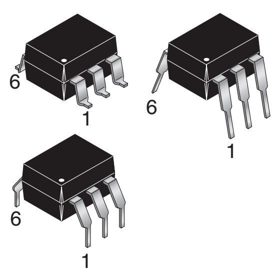


SCHEMATIC



PIN 1. ANODE
2. CATHODE
3. NO CONNECTION
4. EMITTER
5. COLLECTOR
6. BASE

BLACK PACKAGE (NO -M SUFFIX)



DESCRIPTION

The general purpose optocouplers consist of a gallium arsenide infrared emitting diode driving a silicon phototransistor in a 6-pin dual in-line package.

FEATURES

- Also available in white package by specifying -M suffix, eg. 4N25-M
- UL recognized (File # E90700)
- VDE recognized (File # 94766)
  - Add option V for white package (e.g., 4N25V-M)
  - Add option 300 for black package (e.g., 4N25.300)

APPLICATIONS

- Power supply regulators
- Digital logic inputs
- Microprocessor inputs

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C unless otherwise specified)

Parameter	Symbol	Value	Units
TOTAL DEVICE			
Storage Temperature	T_{STG}	-55 to +150	°C
Operating Temperature	T_{OPR}	-55 to +100	°C
Lead Solder Temperature	T_{SOL}	260 for 10 sec	°C
Total Device Power Dissipation @ T_A = 25°C	P_D	250	mW
Derate above 25°C		3.3 (non-M), 2.94 (-M)	
EMITTER			
DC/Average Forward Input Current	I_F	100 (non-M), 60 (-M)	mA
Reverse Input Voltage	V_R	6	V
Forward Current - Peak (300µs, 2% Duty Cycle)	I_F(pk)	3	A
LED Power Dissipation @ T_A = 25°C	P_D	150 (non-M), 120 (-M)	mW
Derate above 25°C		2.0 (non-M), 1.41 (-M)	mW/°C
DETECTOR			
Collector-Emitter Voltage	V_{CEO}	30	V
Collector-Base Voltage	V_{CBO}	70	V
Emitter-Collector Voltage	V_{ECO}	7	V
Detector Power Dissipation @ T_A = 25°C	P_D	150	mW
Derate above 25°C		2.0 (non-M), 1.76 (-M)	mW/°C

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise specified)

INDIVIDUAL COMPONENT CHARACTERISTICS

Parameter	Test Conditions	Symbol	Min	Typ*	Max	Unit
EMITTER						
Input Forward Voltage	(I_F = 10 mA)	V_F		1.18	1.50	V
Reverse Leakage Current	(V_R = 6.0 V)	I_R		0.001	10	µA
DETECTOR						
Collector-Emitter Breakdown Voltage	(I_C = 1.0 mA, I_F = 0)	BV_{CEO}	30	100		V
Collector-Base Breakdown Voltage	(I_C = 100 µA, I_F = 0)	BV_{CBO}	70	120		V
Emitter-Collector Breakdown Voltage	(I_E = 100 µA, I_F = 0)	BV_{ECO}	7	10		V
Collector-Emitter Dark Current	(V_{CE} = 10 V, I_F = 0)	I_{CEO}		1	50	nA
Collector-Base Dark Current	(V_{CB} = 10 V)	I_{CBO}			20	nA
Capacitance	(V_{CE} = 0 V, f = 1 MHz)	C_{CE}		8		pF

ISOLATION CHARACTERISTICS

Characteristic	Test Conditions	Symbol	Min	Typ*	Max	Units
Input-Output Isolation Voltage	(Non '-M', Black Package) (f = 60 Hz, t = 1 min)	V_{ISO}	5300			Vac(rms)
	('-M', White Package) (f = 60 Hz, t = 1 sec)		7500			Vac(pk)
Isolation Resistance	(V_{I-O} = 500 VDC)	R_{ISO}	10^{11}			Ω
Isolation Capacitance	(V_{I-O} = &, f = 1 MHz)	C_{ISO}		0.5		pF
	('-M' White Package)			0.2	2	pF

Note
* Typical values at T_A = 25°C

TRANSFER CHARACTERISTICS (T_A = 25°C Unless otherwise specified.)							
DC Characteristic	**Test Conditions**	**Symbol**	**Device**	**Min**	**Typ***	**Max**	**Unit**
Current Transfer Ratio, Collector to Emitter	(I_F = 10 mA, V_{CE} = 10 V)	CTR	4N35 4N36 4N37	100			%
			H11A1	50			
			H11A5	30			
			4N25 4N26 H11A2 H11A3	20			
			4N27 4N28 H11A4	10			
	(I_F = 10 mA, V_{CE} = 10 V, T_A = -55°C)		4N35 4N36 4N37	40			
	(I_F = 10 mA, V_{CE} = 10 V, T_A = +100°C)		4N35 4N36 4N37	40			
Collector-Emitter Saturation Voltage	(I_C = 2 mA, I_F = 50 mA)	$V_{CE\ (SAT)}$	4N25 4N26 4N27 4N28			0.5	V
	(I_C = 0.5 mA, I_F = 10 mA)		4N35 4N36 4N37			0.3	
			H11A1 H11A2 H11A3 H11A4 H11A5			0.4	
AC Characteristic Non-Saturated Turn-on Time	(I_F = 10 mA, V_{CC} = 10 V, R_L = 100Ω) (Fig.20)	T_{ON}	4N25 4N26 4N27 4N28 H11A1 H11A2 H11A3 H11A4 H11A5		2		µs
Non Saturated Turn-on Time	(I_C = 2 mA, V_{CC} = 10 V, R_L = 100Ω) (Fig.20)	T_{ON}	4N35 4N36 4N37		2	10	µs

TRANSFER CHARACTERISTICS (T_A = 25°C Unless otherwise specified.) (Continued)

AC Characteristic	Test Conditions	Symbol	Device	Min	Typ*	Max	Unit
Turn-off Time	(I_F = 10 mA, V_{CC} = 10 V, R_L = 100Ω) (Fig.20)	T_{OFF}	4N25 4N26 4N27 4N28 H11A1 H11A2 H11A3 H11A4 H11A5		2		μs
	(I_C = 2 mA, V_{CC} = 10 V, R_L = 100Ω) (Fig.20)		4N35 4N36 4N37		2	10	

* Typical values at T_A = 25°C

TYPICAL PERFORMANCE CURVES

Fig. 1 LED Forward Voltage vs. Forward Current (Black Package)

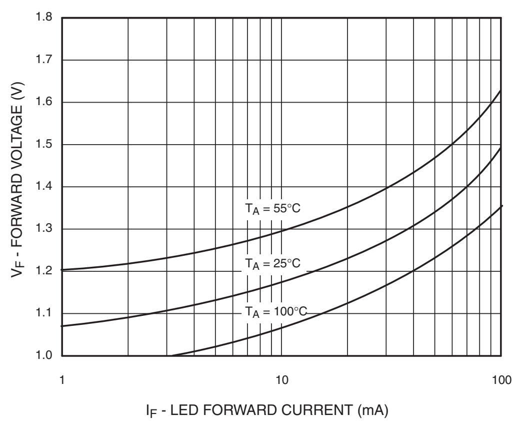


Fig. 2 LED Forward Voltage vs. Forward Current (White Package)

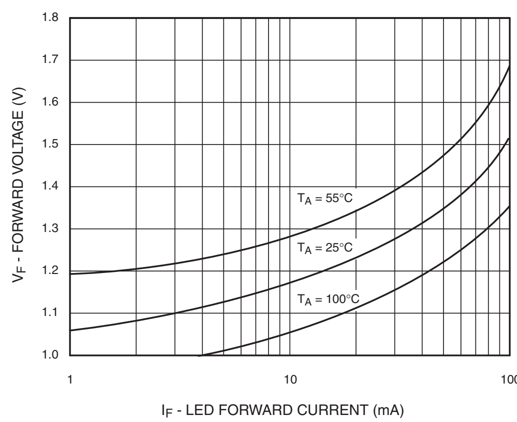


Fig.3 Normalized CTR vs. Forward Current (Black Package)

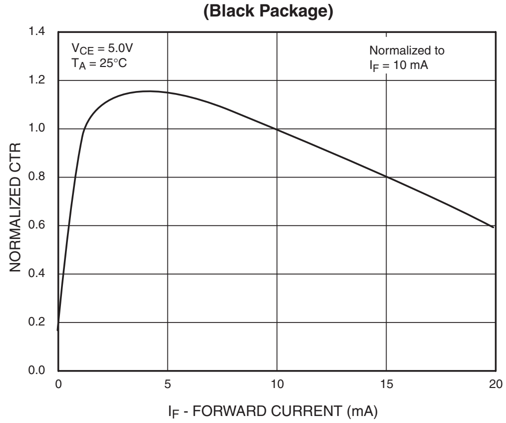


Fig.4 Normalized CTR vs. Forward Current (White Package)

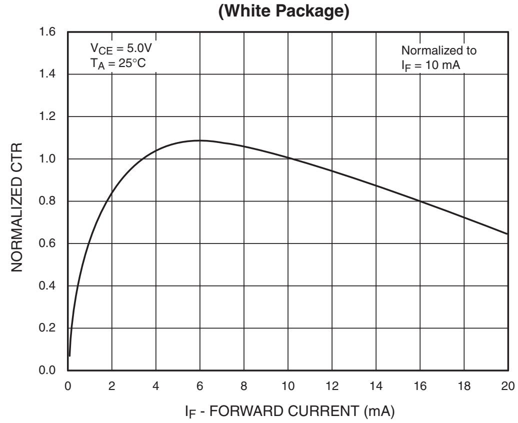


Fig. 5 Normalized CTR vs. Ambient Temperature (Black Package)

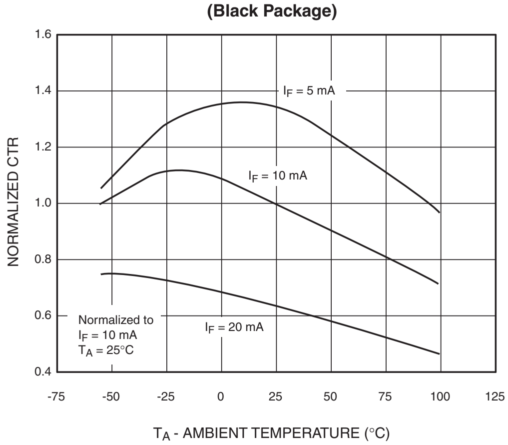


Fig. 6 Normalized CTR vs. Ambient Temperature (White Package)

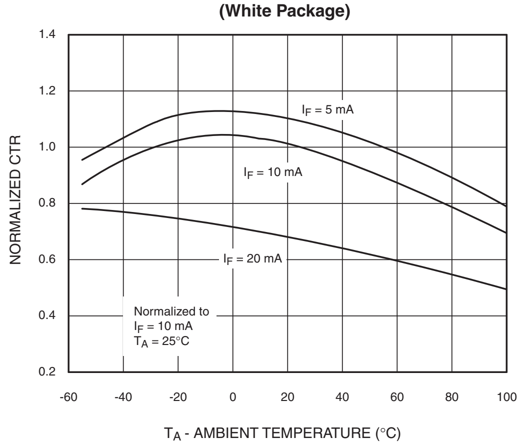


Fig. 7 CTR vs. RBE (Unsaturated) (Black Package)

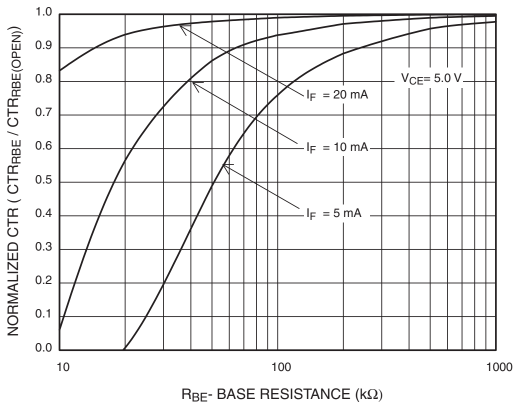


Fig. 8 CTR vs. RBE (Unsaturated) (White Package)

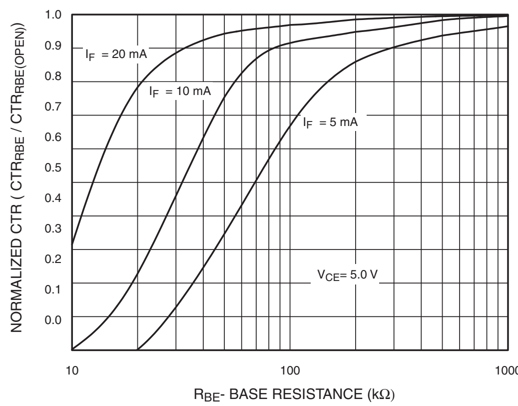


Fig. 9 CTR vs. RBE (Saturated) (Black Package)

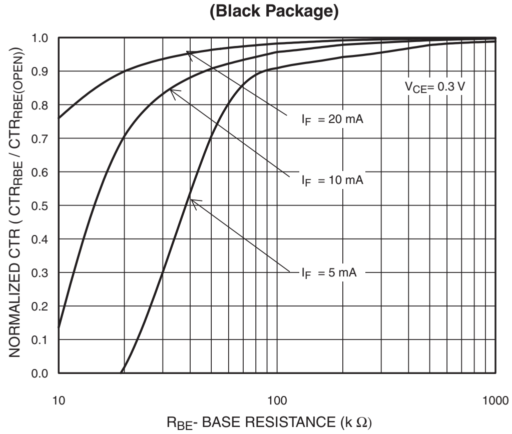


Fig. 10 CTR vs. RBE (Saturated) (White Package)

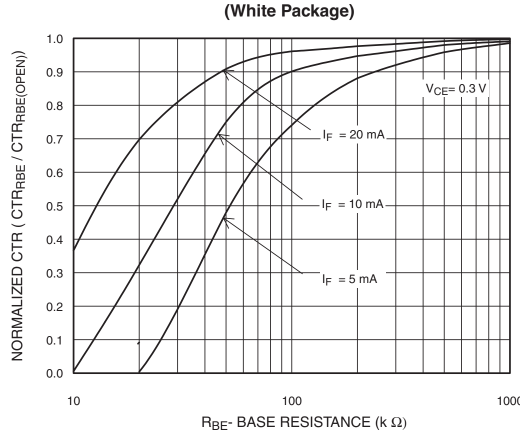


Fig. 11 Collector-Emitter Saturation Voltage vs Collector Current (Black Package)

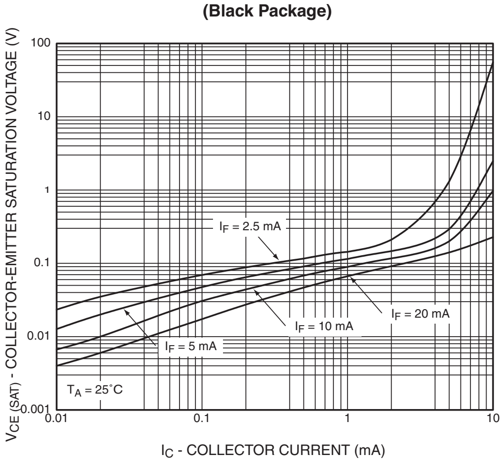


Fig. 12 Collector-Emitter Saturation Voltage vs Collector Current (White Package)

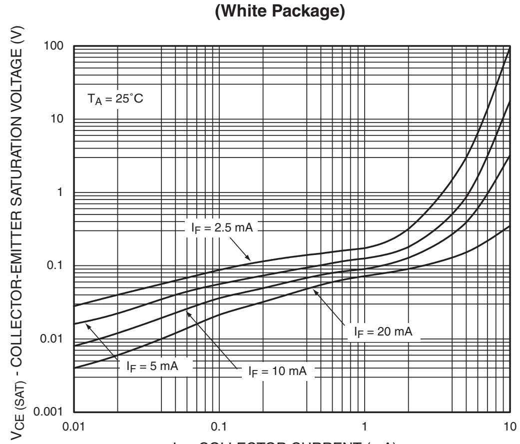


Fig. 13 Switching Speed vs. Load Resistor (Black Package)

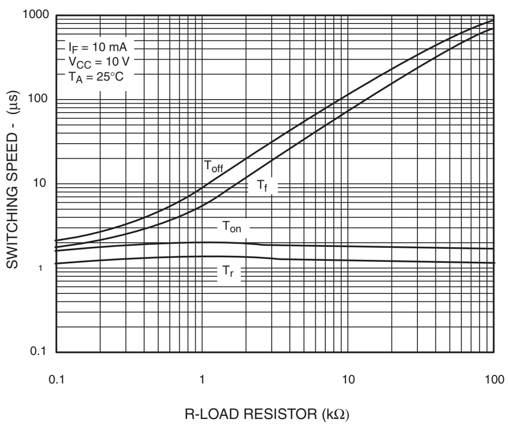


Fig. 14 Switching Speed vs. Load Resistor (White Package)

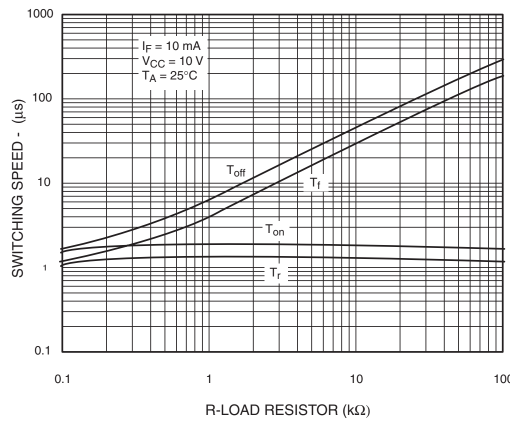


Fig. 15 Normalized t_{on} vs. R_{BE} (Black Package)

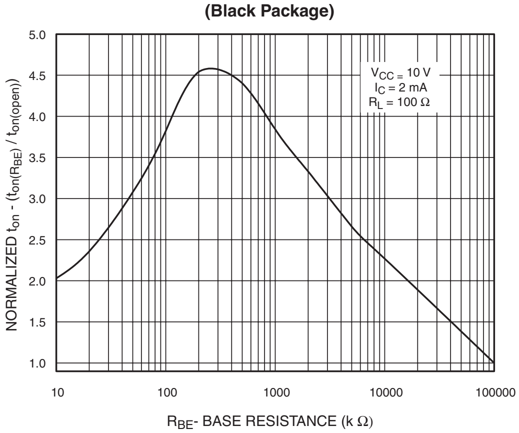


Fig. 16 Normalized t_{on} vs. R_{BE} (White Package)

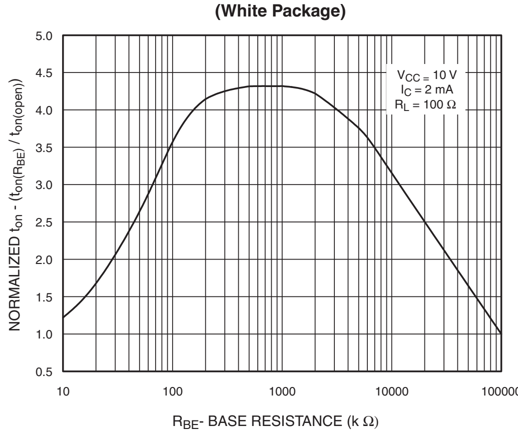


Fig. 17 Normalized t_{off} vs. R_{BE} (Black Package)

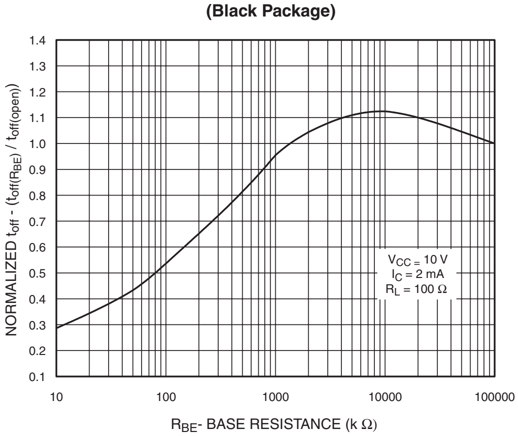
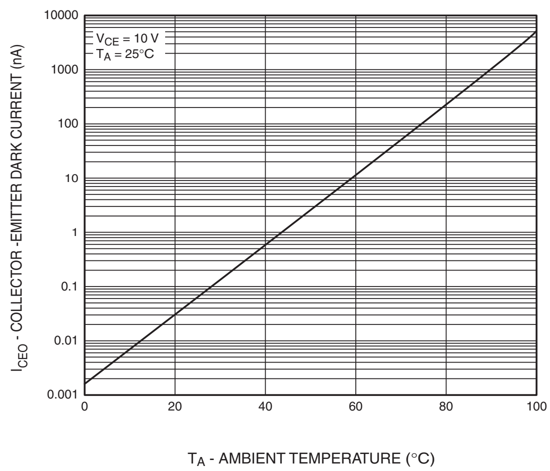


Fig. 18 Normalized t_{off} vs. R_{BE} (White Package)

Fig. 19 Dark Current vs. Ambient Temperature



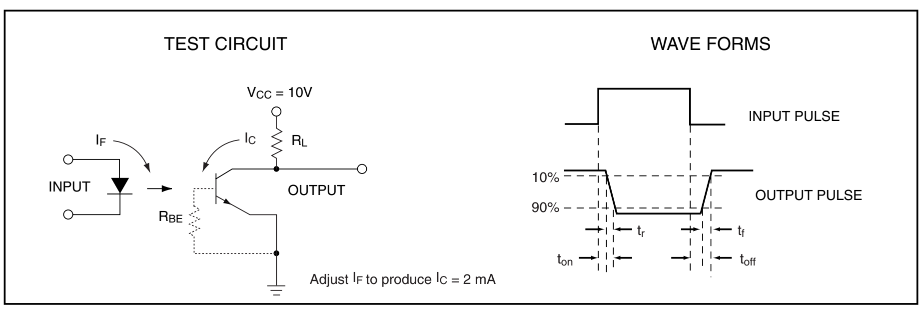


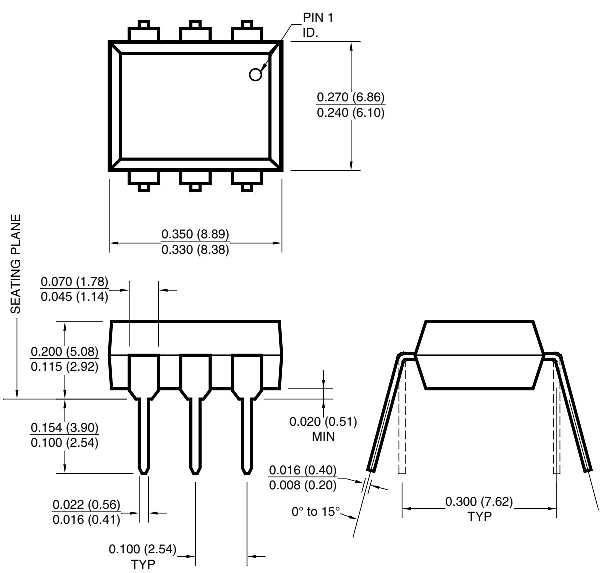
Figure 20. Switching Time Test Circuit and Waveforms

GENERAL PURPOSE 6-PIN PHOTOTRANSISTOR OPTOCOUPLERS

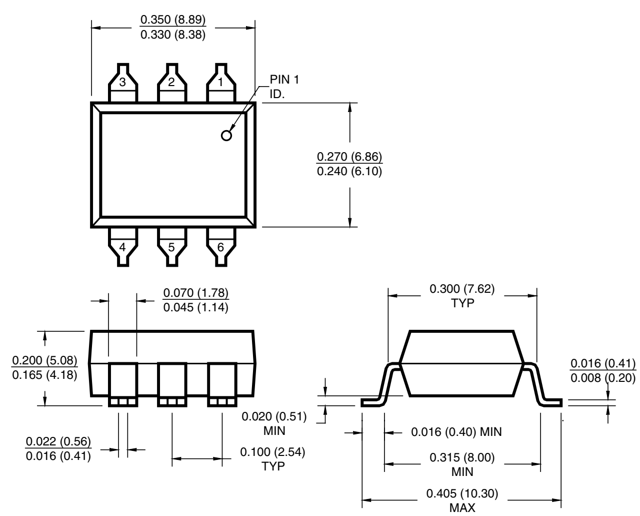
4N25	4N26	4N27	4N28	4N35	4N36
4N37	H11A1	H11A2	H11A3	H11A4	H11A5

Black Package (No -M Suffix)

Package Dimensions (Through Hole)

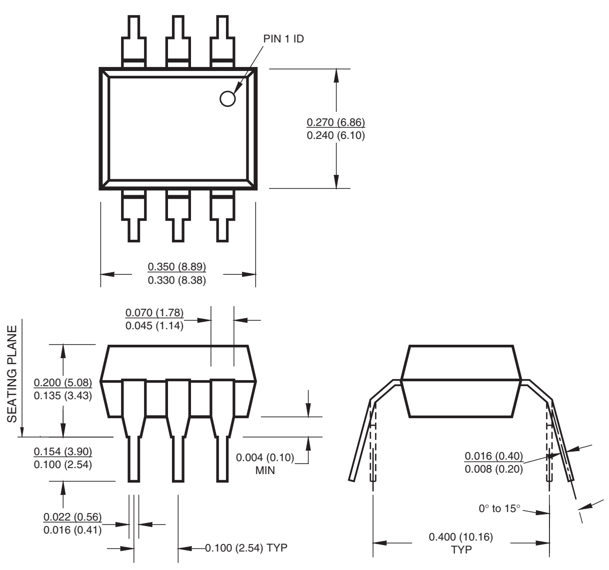


Package Dimensions (Surface Mount)

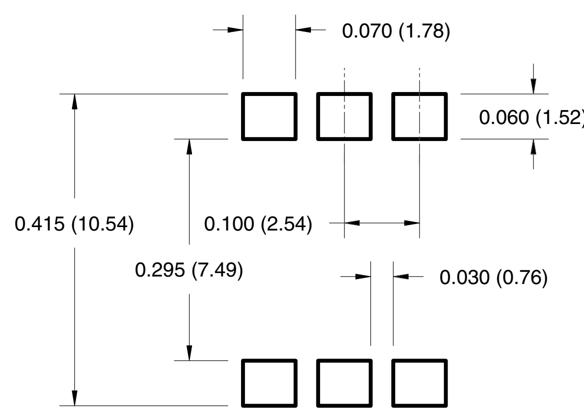


Lead Coplanarity : 0.004 (0.10) MAX

Package Dimensions (0.4" Lead Spacing)



Recommended Pad Layout for Surface Mount Leadform



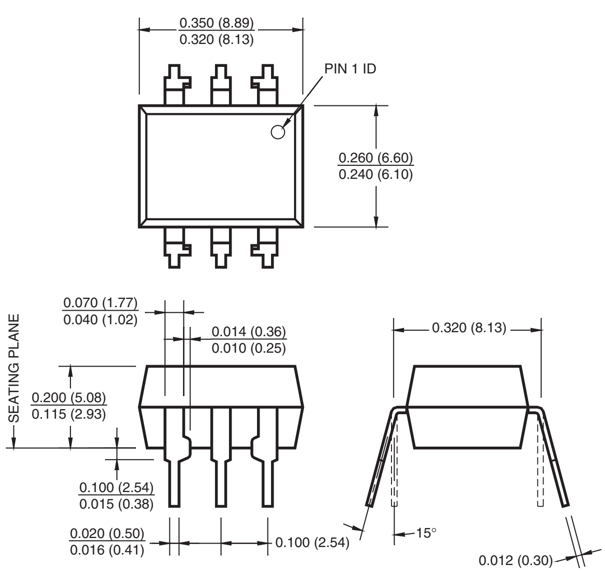
NOTE
All dimensions are in inches (millimeters)

GENERAL PURPOSE 6-PIN PHOTOTRANSISTOR OPTOCOUPLERS

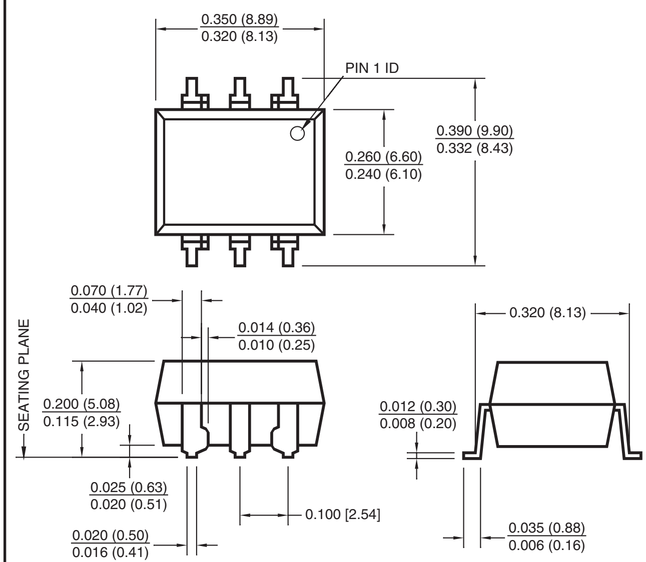
4N25	4N26	4N27	4N28	4N35	4N36
4N37	H11A1	H11A2	H11A3	H11A4	H11A5

White Package (-M Suffix)

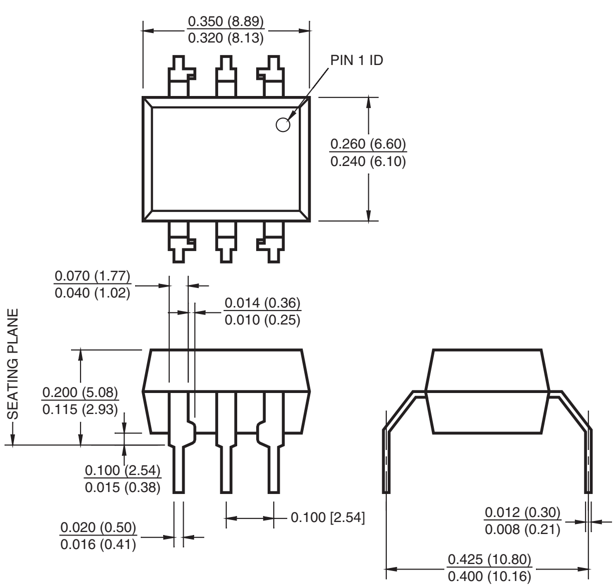
Package Dimensions (Through Hole)



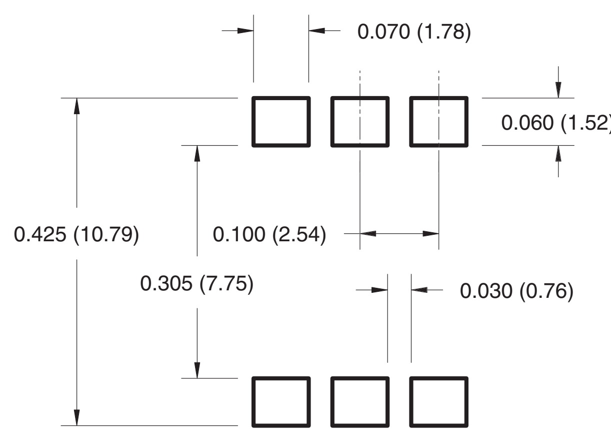
Package Dimensions (Surface Mount)



Package Dimensions (0.4" Lead Spacing)



Recommended Pad Layout for Surface Mount Leadform

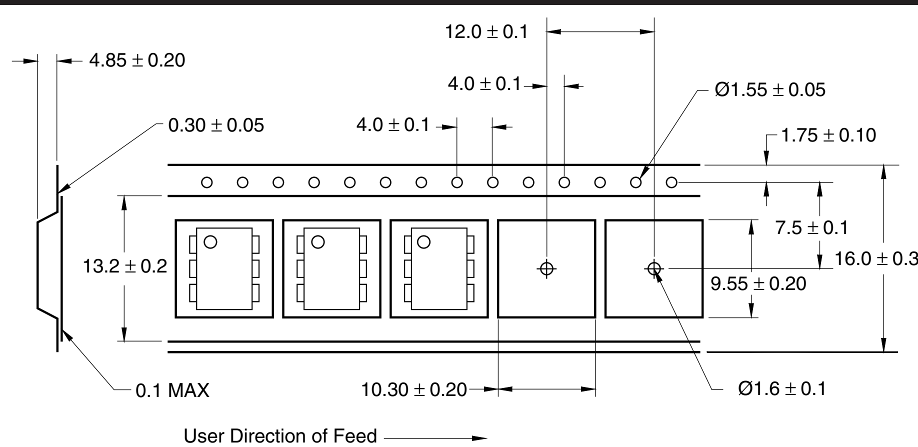


NOTE
All dimensions are in inches (millimeters)

ORDERING INFORMATION

Order Entry Identifier		
Black Package (No Suffix)	**White Package (-M Suffix)**	**Option**
.S	S	Surface Mount Lead Bend
.SD	SR2	Surface Mount; Tape and reel
.W	T	0.4" Lead Spacing
.300	V	VDE 0884
.300W	TV	VDE 0884, 0.4" Lead Spacing
.3S	SV	VDE 0884, Surface Mount
.3SD	SR2V	VDE 0884, Surface Mount, Tape & Reel

QT Carrier Tape Specifications (Black Package, No Suffix)



QT Carrier Tape Specifications (White Package, -M Suffix)